## The 2nd RIEC International Workshop on Spintronics

## -MgO-based Magnetic Tunnel Junctions-

**Date:** February 15th (Thu.) – 16th (Fri.), 2007

-19:30

Venue: Laboratory for Nanoelectronics and Spintronics, RIEC Tohoku University

## Program (tentative)

Feb. 15 <sup>th</sup> (Thu.)	
9:10	Opening address H. Ohno (Organizer, Tohoku University, Japan)
9:20	Opening remark T. Miyazaki (Tohoku University, Japan)
9:30	Theory of spin-dependent tunneling in MgO-based junctions  J. Mathon (City University London, UK)
10:10	Theoretical study on coherent tunneling in half-metallic Heusler alloys/MgO junctions M. Shirai (Tohoku University, Japan)
10:40	Coffee break
11:10	Recent progress in fully epitaxial Mg-O based MTJs  S. Yuasa (Advanced Industrial Science and Technology, Japan)
11:50	Giant tunnel magnetoresistance for exchange biased- and pseudo-spin valve CoFeB/MgO/CoFeB magnetic tunnel junctions  Y. M. Lee (Tohoku University, Japan)
12:20	Lunch
14:00	Characterazations on the polycrystalline CoFeB/MgO/CoFeB-based magnetic tunnel junctions  Y. S. Choi (Canon Anelva, Co., Japan)
14:40	XPS, STS and STEM studies on MgO tunnel barrier layers in MTJ (tentative) J. Read (Cornell University, USA)
15:10	Crystallographic structure and giant TMR of CoFeB/MgO/CoFeB-MTJs  M. Tsunoda (Tohoku University, Japan)
15:40	Coffee break
16:10	MgO double tunnel junctions  M. Coey (University of Dublin, Ireland)
16:50 (-17:20	How to play with the fastidious MgO applicable to STT-MRAM  K. H. Shin (Korea Institute of Science and Technology, Korea)
18:00	Banquet —Sendai Kokusai Hotel; "Steakery Thirty"—

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## Feb. 16<sup>th</sup> (Fri.)

9:30	J. Sun (Thomas J. Watson Research Center, IBM, USA)
10:10	Spin Transfer Switching in MTJ with Nano-Second Pulse Widths
	Y. Huai (Grandis Inc., USA)
10:50	Coffee break
11:10	Current-induced magnetization switching and thermal stability in nano-scale MgO based magnetic tunnel junctions  J. Hayakawa (Hitachi Ltd., Japan)
11:40	Large power microwave excitations induced by spin-transfer in MgO-based magnetic tunnel junctions  A. Deac (Osaka University, Japan)
12:10	Lunch
14:00	Spin polarized tunneling in MgO based magnetic tunnel junctions S. Parkin (Almaden Research Center, IBM, USA)
14:40	Giant TMR at room temperature using Co-based Heusler alloy electrodes and a MgO barrier  K. Inomata (National Institute for Materials Science, Japan)
15:10	Spin-dependent tunneling in fully epitaxial magnetic tunnel junctions with a Heusler alloy thin film and a MgO tunnel barrier  M. Yamamoto (Hokkaido University, Japan)
15:40	Coffee break
16:10	Tunnel magnetoresistance in MTJs with Co <sub>2</sub> MnSi electrode and MgO barrier  M. Oogane (Tohoku University, Japan)
16:40	Thermal stability of exchange-couple trilayers for high density magnetic random access memory  S. H. Lim (Korea University, Korea)
17:10 -17:20	Closing address  H. Ohno (Tohoku University, Japan)